NSN 5961-01-184-2827

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Inclosure Material:

Metal

Overall Length:

1.252 inches

Overall Height:

0.295 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

T0-66

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

500.0 breakdown voltage, collector-to-base, emitter open and 300.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

1.00 amperes source cutoff current

Power Rating Per Characteristic:

35.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

25.0 degrees celsius case

Special Features:

0.172 in. Terminal Ig; junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0